



FAST RECOVERY RECTIFIER DIODES

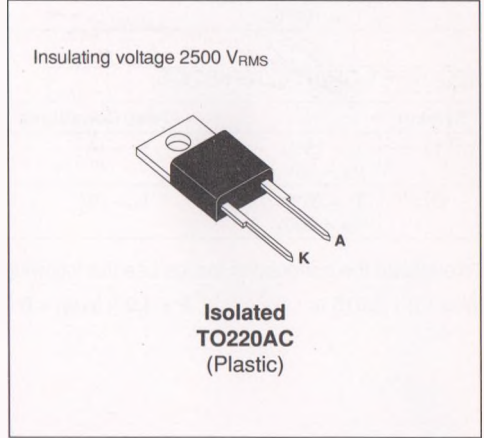
- HIGH VOLTAGE CAPABILITY
- FAST AND SOFT RECOVERY
- THE SPECIFICATIONS AND CURVES ENABLE THE DETERMINATION OF t_{rr} AND I_{RM} AT 100°C UNDER USERS CONDITIONS
- INSULATED

APPLICATIONS

- MOTOR CONTROLS AND CONVERTERS
- SWITCHMODE POWER SUPPLIES

DESCRIPTION

Fast recovery rectifiers suited for applications in combination with superswitch transistors.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I_{FRM}	Repetitive Peak Forward Current	$t_p \leq 20\mu s$	120	A
$I_F (RMS)$	RMS Forward Current		16	A
$I_F (AV)$	Average Forward Current	$T_C = 100^\circ C$ $\delta = 0.5$	10	A
I_{FSM}	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	120	A
P_{tot}	Power Dissipation	$T_C = 100^\circ C$	20	W
T_{stg} T_J	Storage and Junction Temperature Range		- 40 to 150	°C

Symbol	Parameter	ESM 765PI-		Unit
		600	800	
V_{RRM}	Repetitive Peak Reverse Voltage	600	800	V
V_{RSM}	Non Repetitive Peak Reverse Voltage	600	800	V

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th (j-c)}$	Junction-case	3.5	°C/W

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I _R	T _j = 25°C	V _R = V _{RRM}			20	μA
	T _j = 100°C				1	mA
V _F	T _j = 25°C	I _F = 10A			1.4	V
	T _j = 100°C				1.35	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
t _{rr}	T _j = 25°C V _R = 30V	I _F = 1A di _F /dt = - 15A/μs			300	ns
Q _{rr}	T _j = 25°C V _R = 200V	I _F = 10A di _F /dt = - 50A/μs		2.3		μC

To evaluate the conduction losses use the following equations :

$$V_F = 1.2 + 0.015 I_F$$

$$P = 1.2 \times I_{F(AV)} + 0.015 I_F^2_{(RMS)}$$

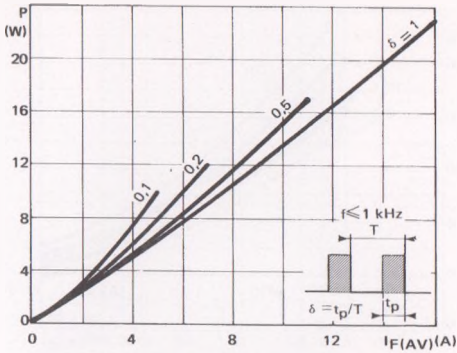


FIGURE 1: Low frequency power losses versus average current

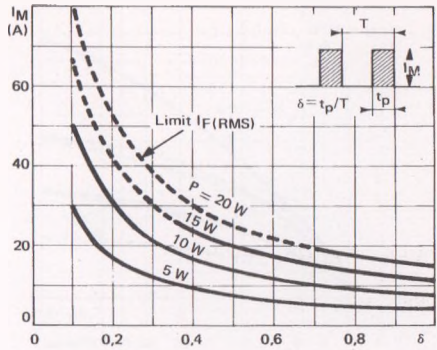


FIGURE 2: Peak current versus form factor

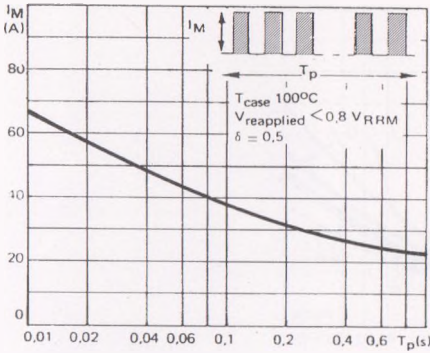


FIGURE 3: Non repetitive peak surge current versus overload duration

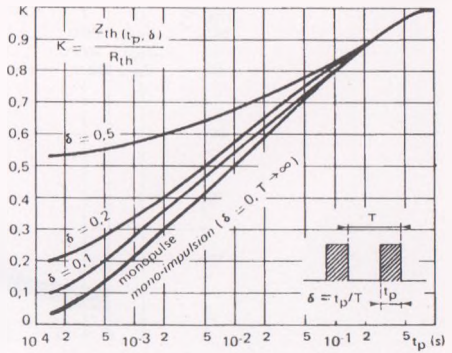


FIGURE 4: Thermal impedance versus pulse width

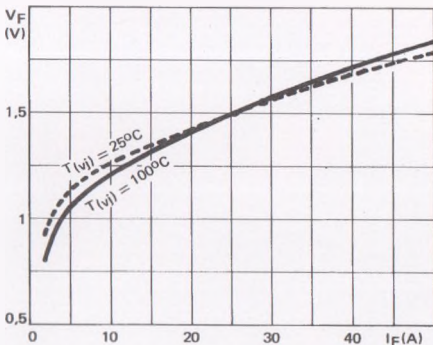


FIGURE 5: Forward voltage drop versus forward current

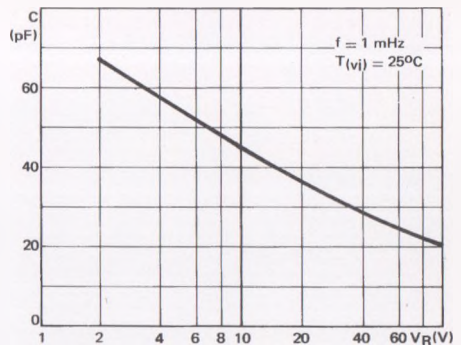


FIGURE 6: Capacitance versus applied reverse voltage

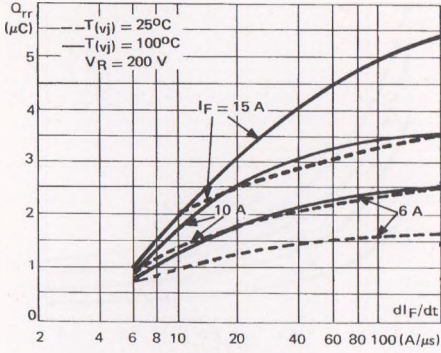


FIGURE 7: Recovery charge versus dI_F/dt

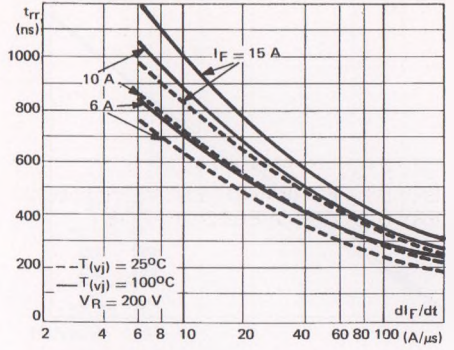


FIGURE 8: Recovery time versus dI_F/dt

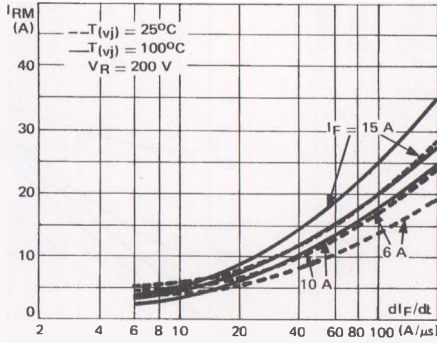


FIGURE 9: Peak reverse current versus dI_F/dt